T ip O scillation of D endritic Patterns in a Phase Field M odel

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A bstract

We study dendritic growth numerically with a phase eld model. T ip oscillation and regular side-branching are observed in a parameter region where the anisotropies of the surface tension and the kinetic e ect compete. The transition from a needle pattern to a dendritic pattern is conjectured to be a supercritical H opf bifurcation.

1 Introduction

C rystal grow th has been intensively studied as a problem of pattern form ation far from equilibrium .[1, 2] D endrites are typical grow th patterns found in crystal grow th exhibited by m ost m etal alloys and som e plastic crystals.[3, 4] T he phase

eld model, which has the form of the G inzburg-Landau equation coupled with a di usion equation, is a useful model for such grow th patterns. [5, 6, 7, 8] For melt grow th, the G inzburg-Landau equation represents the dynam ics of a phase transition from a liquid phase to a solid phase, and it is coupled with a heat conduction equation for the latent heat generated at the grow ing interface.

The standard theory of crystal grow th predicts that a needle crystal selected by the solvability condition is stable, and side branches are produced owing to them allooise.[9, 10] However, there are some experiments suggesting that side branches may appear as a result of regular tip oscillations.[11, 12, 13, 14] Liu and Goldenfeld investigated the linear stability of a steady needle crystal using the boundary layer model and found an instability in a certain range of param – eter values of the surface tension and kinetic coe cients.[15] Ihle numerically investigated the competition between the kinetic and surface tension anisotropy in dendritic grow th using a fully dynam ical front-tracking method and found oscillatory grow th.[16] How ever, the numerical results do not seem to exhibit clear oscillation, probably owing to numerical noise resulting from the discretization. Such numerical noise e ects seem to be small in the phase eld model. We have num erically investigated the competition between the kinetic and surface tension anisotropy using a phase eld model and found that the growth direction changes from hl0i to hl1i as the kinetic coe cient is changed.[17] This is a transition from a surface tension dendrite to a kinetic dendrite. Such transitions have been observed in experim ents of viscous ngering and NH₄Clcrystal.[18, 19] In a previous work, we found that com plicated patterns grow from sm all round seeds in an interm ediate parameter region where the two anisotropies compete. However, we could not nd clear limit cycle oscillation of the tip growth. In this work, we consider the situation in which the anisotropy parameter is changed slow ly, in a stepwise manner, and nd a transition from a steady needle pattern to a tip-oscillating dendrite.

2 Tip oscillation of dendritic patterns in the phase eld m odel

The phase eld model in two dimensions is written

$$() @_{t}p = fp u(1 p^{2})g(1 p^{2}) + @_{x}fW ()^{2}@_{x}p W ()W ^{0}()@_{y}pg + @_{y}fW ()^{2}@_{y}p + W ()W ^{0}()@_{x}pg; @_{t}u = Dr^{2}u + @_{t}p=2;$$
 (1)

where p(x;y;t) is the order parameter, is a coupling constant, and () is the time constant for the order parameter, with = $\arctan(\theta_y p = \theta_x p)$ the angle between the normal direction of the contour of constant p and the x axis. The solid and liquid phase correspond, respectively, to p = 1 and p = 1. The normalized tem perature is denoted by $u(x;y;t) = (T T_M) = (L=C_p)$ where $T(x;y;t);T_M$; L and C_p are, respectively, the tem perature, the melting tem perature, the latent heat and the speci c heat. The di usion constant for u is denoted by D, and W²() is an anisotropic di usion constant for the order parameter. The generalized G ibbs-Thom son condition (the W ilson-Frenkel form ula),

$$u_i = d_0()$$
 () v_n ; (2)

is assumed for the sharp interface model, where u_i is the normalized temperature at the interface, $d_0()$; ; () and v_n denote, respectively, the anisotropic capillary length, the interface curvature, the anisotropic kinetic coeccient and the normal interface velocity. Karm a and Rappel derived the values of $d_0()$ and () in the sharp-interface limit to the phase eld model as [8]

$$d_{0}() = \frac{I}{J} fW() + W"()g;$$

$$() = \frac{I}{J} \frac{()}{W()} 1 \frac{W^{2}()}{2D()} \frac{K + JF}{I};$$
(3)

where $I = 2^{p} \overline{2}=3; J = 16=15; K = 0.13604$ and $F = {p \overline{2} \ln 2}$. If () = W²() and the coupling constant is assumed to be = (2ID)=(K + JF), the anisotropic kinetic coe cient becomes zero, and the standard G ibbs-Thom son condition is realized. Karm a and Rappel performed numerical simulations for this case, and obtained dendrites with tip velocities and tip shapes that agree well with the theory based on the solvability condition. The growth law v² = const., where v is the steady growth velocity of the tip and is the tip radius, is then satis ed.

We perform ed num erical sin ulations of the phase eld model with an anisotropic kinetic coe cient. We found that if the kinetic e ect is included, the tip radius does not become sharper and sharper, in contrast to the case in which there is no kinetic e ect and the relation $v^2 = \text{const.}$ is not satisfied, when the supercooling is close to 1.[20] In this paper, we study the competition of the surface tension anisotropy and the kinetic coe cient anisotropy. Four-fold rotational symmetry is assumed for the anisotropy: W() = $1 + e_4 \cos(4)$ and () = W()f1 + $e_k \cos(4)$ g, where e_4 and e_k denote the anisotropy parameters of the surface tension and the kinetic coe cient. The coupling constant and the di usion constant are chosen as = 1:9ID = (K + JF) and D = 2. This choice of parameter values corresponds to the anisotropy coe - cients $d_0() / 1$ $15e_4 \cos(4)$ and () / $0:05 + (e_k - 0:95e_4) \cos(4)$ in the sharp interface limit, owing to Eq. (3).



Figure 1: Needle pattern exhibited by the phase eld model with four-fold rotational symmetry for $e_4 = 0.06$; = 0.7 and $e_k = 0.07$.

When e_k is larger than $0.95e_4$, the hlli growth becomes favorable, owing to the kinetic elect. Numerical simulations were performed using the nite dimension method with x = 0.4 and t = 0.015. The system size was I_x $L_y = 640$ 160. The uniform undercooling u = w as employed as the initial condition. M incor-symmetric boundary conditions were used at x = 0 and $y = 0; L_y$ and the xed boundary conditions p = 1 and u = w were used at $x = L_x$. The parameters and e_4 were xed as = 0.7 and $e_4 = 0.06$, and the parameter e_k for the kinetic anisotropy was changed step by step.

The process used in our numerical simulation is as follows. If the tip of the dendritic pattern reaches x = 600, the growth for the parameter e_k is stopped, and the numerical data for the order parameter and the tem perature are saved. The order parameter and the tem perature proles in the tip region



Figure 2: (a) D endritic pattern with regular side branches at $e_4 = 0.06$; = 0.7and $e_k = 0.08$. (b) T in e evolution of the interface temperature u(y;t) for y = 20. (c) Amplitude j u(y) jof the oscillation as a function of y.

(p(x;y); u(x;y) for x > 520) are used as the initial conditions for the parameter e_k at the next step, that is, p(x;y;0) = p(x 520;y); u(x;y;0) = u(x 520;y).

Figure 1 displays a snapshot of a needle pattern for $e_k = 0.07$. This needle pattern is growing in the hl0i direction, owing to the surface tension anisotropy. As the parameter e_k is increased, the growth direction changes from the hl0i direction to the hl1i direction due to the kinetic e ect. In region of intermediate values of the parameter e_k , a dendritic pattern with side branches appears. Figure 2 (a) displays a dendritic pattern for $e_k = 0.08$. Regular side branching is seen. The interface temperature u(y;t) is evaluated for each y as the temperature at the position (x;y) where p(x;y) = 0 is satistic ed. For this parameter value, the average tip velocity is approximately v = 0.265, and the di usion length l = 2D = v 15. The system size is su ciently larger than the di usion length. Figure 2 (a) displays a snapshot pattern at the instant that the tip reaches the position x = 600, and the e ect of the boundary at $x = L_x = 640$ is not yet in portant. Figure 2 (b) displays the interface tem perature at y = 20. The interface tem perature and the curvature oscillate regularly



Figure 3: Am plitude of the oscillation j u(y) jat y = 20 as a function of e_k .

at this value of the param eter. Figure 2 (c) displays the am plitude of the oscillation j u(y) j = maxu(y;t) minu(y;t) as a function of y, where maxu(y;t) and m in u (y;t) are, respectively, the m axim um and m in im um values in the oscillatory tim e evolution of u (y;t). This am plitude increases m onotonically, but, it does not seem to t a curve such as $\exp(cs^{1-4})$ or $\exp(cs)$, where s is the arc length along the interface and c is a constant, as is expected from some theories. It seems, rather, to t a linear curve, cs, although we do not understand the reason for this. Figure 3 displays the amplitude of the oscillation j u(y) jaty = 20 as a function of e_k . As seen, there is a transition from a stationary state to oscillatory grow th, and the amplitude increases continuously from zero; that is, there is no jump at the transition. The transition is therefore concluded to be a supercritical H opf bifurcation. This lim it cycle process can be interpreted as follows. The surface tension dendrite grows in the hl0i direction. The side branches grow in the hlli direction, owing to the kinetic e ect. Then, the dendritic tip becom es round, the radius of curvature of the tip region increases, and the growth velocity in the h10i direction decreases. As the velocity is decreased, the kinetic e ect, which is proportional to the growth velocity, becomes weak, and the surface tension e ect become relatively large. Then, growth in the hl0i becom es dom inant, and the velocity in the hl0i direction increases. As the growth velocity increases, the kinetic e ect becomes relatively large, and the side branches grow in the hlli direction again. In this way, a negative feedback acts between the tip velocity in the h10i direction and the kinetic e ect, and a stable lim it cycle appears.

Next, we consider the transition for kinetic dendrites. If $e_k < 0$, $e_4 < 0$ and e_k is su ciently smaller than e_4 , a steady needle pattern grows in the hl0i direction, owing to the kinetic anisotropy. As e_k remaining less than 0 is increased, the kinetic anisotropy becomes relatively weak, and the surface tension becomes dominant. Then a transition from hl0i grow th to hl1i grow th occurs. In the simulations, the parameters and e_4 were xed as = 0.7 and $e_4 = 0.06$, and the parameter e_k was changed stepwise. The system size was



Figure 4: (a) Needle pattern for $e_4 = 0.06$; = 0.7 and $e_k = 0.088$. (b) Snapshot of the pattern for $e_4 = 0.06$; = 0.7 and $e_k = 0.085$. (c) T in e evolution of the interface temperature u (y;t) at y = 20.

 L_x $L_y = 640$ 120. Figure 4 (a) displays a needle pattern for $e_k =$ 0:088.The needle pattern is marginally stable for e_k 0:087, and it becom es unstable for $e_k > 0.086$. Figure 4 (b) displays the snapshot of a pattern for $e_k = 0.086$. 0:085. Side branches develop in the tip region, and the growth of the side branches does not saturate. Figure 4 (c) displays the tem poral evolution of the interface tem perature u (y;t) at y = 20. The amplitude of the oscillation of the interface tem perature grows but does not saturate. The side branches develop and they become main branches if Ly is su ciently large. The negative feedback does not act in this case. If the side branches grow, owing to the surface tension e ect, the dendritic tip becomes more round and the growth velocity in the hl0i direction decreases. Then the kinetic e ect becomes further weakened, the surface tension e ect becom es m ore dom inant, and the growth in the hlli direction does not saturate.

E lucidation of the oscillatory growth caused by the competition between two types of anisotropies is the main result of this paper. However, we also demonstrate a transition to the tip oscillation of dendritic growth, where the surface tension anisotropy has eight-fold rotational symmetry.[17, 21] In a previous work, we showed the existence of tip oscillation in such a system, but



Figure 5: (a) D endritic pattern for the phase eld model with eight-fold sym – metry for $e_8 = 0.01$ and = 0.65. (b) Amplitude j u(y) jof the oscillation of the interface temperature at y = 18 as a function of e_8 .

have not demonstrated the transition from the needle pattern to the oscillation. The parameter dependence of the oscillatory growth is observed when () = W^{2} (), where W () = 1 + $e_{8} \cos 8$. The coupling constant is chosen to be = (2ID)=(K + JF), so that the kinetic e ect can be neglected. The num erical simulation was performed using the nite di erence method with x = 0.3 and t = 0.01. The system size was L_x $L_{y} = 600$ 90 and the undercooling was xed as = 0.65. Figure 5(a) displays a regularly oscillating dendrite for $e_8 = 0.01$. The interface tem perature is seen to exhibit limit cycle oscillation. Figure 5 (b) displays the am plitude of the oscillation of the interface tem perature j u (y) jat y = 18 as a function of e_3 . A supercritical bifurcation occurs at e₈ 0:045 for this value of the undercooling. There are few real crystals that possess eight-fold rotational sym m etry. However, it is not so unusual for the surface tension to be expressed as d() = $1 + e_4 \cos 4 + e_8 \cos 8$, in which case, the rotational symmetry is four-fold, but the crystal has a component of eight-fold sym m etry. As the param eter $e_4 > 0$ is increased for a xed value of $e_8 > 0$, hl0i growth becomes dominant in comparison with hl1i growth. Tip oscillation appears for a sm all value of e4, but, its am plitude decreases as e4 is increased. T ip oscillation is not observed for $e_4 > 0.016$ when e_3 is xed to 0.01. (The transition to non-oscillatory grow th seems to be discontinuous, with a jump, although this is not entirely clear.) It appears that the competition between hl0i grow th and hl1i grow th m ay be in portant in the realization of tip oscillation.

3 Summary and discussion

We have found a determ inistic transition from a needle pattern to a regularly oscillating dendrite in the phase eld model. This was found in surface tension dendrites with four-fold rotational sym metry and competitive kinetic an isotropy. A similar supercritical transition was found for surface tension dendrites with eight-fold rotational sym m etry without the kinetic e ect. Regularly oscillating surface tension dendrites with four-fold or six-fold rotational symmetry without the kinetic e ect have not yet been found in this model. Regularly oscillating dendrites with side branches possess m irror symmetry as a results of the m ethod used in our num erical simulation. The boundary condition is not, how ever, essential for the oscillation. We have con im ed that a mirror-symmetric dendrite grows naturally in a simulation in which a small needle pattern including a small antisymm etric perturbation is placed in the middle of the left side of the L_x 2L_y box as the initial conditions. These results are not consistent with the linear stability analysis of Liu and Goldenfeld and the simulation of Ihle. They predict oscillatory grow the with antisym metric side branches for both surface tension dendrites and kinetic dendrites. The detailed mechanism of the oscillatory growth is not yet well understood, and its elucidation is left as a future study.

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